

Hall Effect Current Sensors L03S***D15WM Series

Features:

- Open Loop type
- Panel mounting
- Molex connector
- Improved mounting
- Insulated plastic case according to UL94V0

Advantage:

- Excellent accuracy and linearity
- Low temperature drift
- Wide frequency bandwidth
- No insertion loss
- High Immunity To External Interference
- Current overload capability



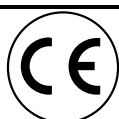
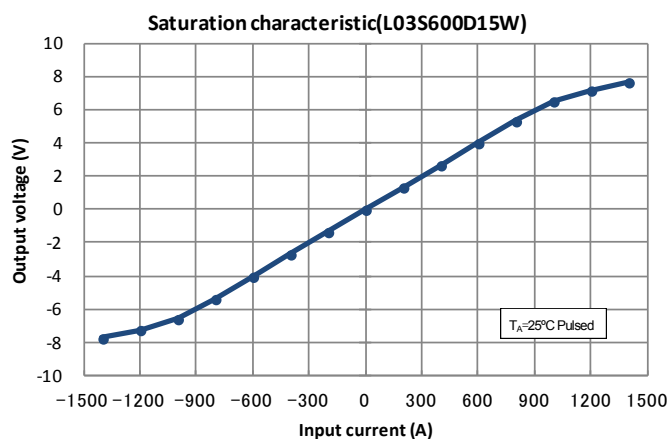
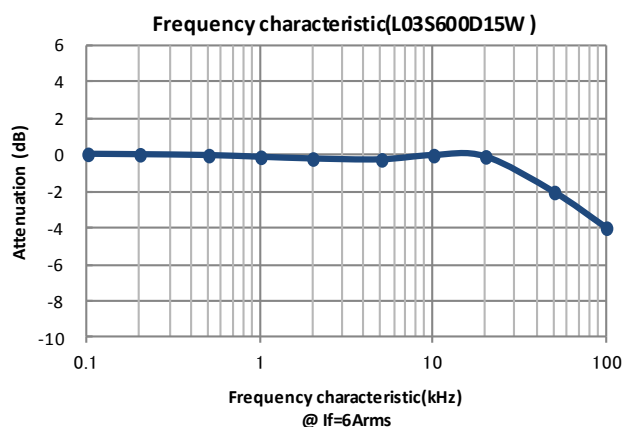
Specifications

 $T_A=25^{\circ}\text{C}$, $V_{CC}=\pm 15\text{V}$, $R_L=10\text{k}\Omega$

Parameters	Symbol	L03S050 D15WM	L03S100 D15WM	L03S200 D15WM	L03S300 D15WM	L03S400 D15WM	L03S500 D15WM	L03S600 D15WM	L03S700 D15WM	L03S800 D15WM
Primary nominal current	I _f	50AT	100AT	200AT	300AT	400AT	500AT	600AT	700AT	800AT
Saturation current	I _{fmax}	≥±150AT	≥±300AT	≥ ±600AT	≥ ±900AT	≥ ±1000A				
Rated output voltage	V _o	4V±0.040V (at If)								
Offset voltage ¹ (at If=0A)	V _{of}	≤ ±40mV	≤ ±30mV							
Output linearity ² (0A~If)	ε _L	≤±1% (at If)								
Power supply voltage	V _{CC}	±15V±5%								
Consumption current	I _{cc}	≤20mA								
Response time ³	t _r	≤10μs (at di/dt=100A/μs)								
Thermal drift of gain ⁴	TcVo	≤ ±0.1%/°C								
Thermal drift of offset	TcVof	≤±2mV/°C	≤±1.0 mV/°C							
Hysteresis error	V _{OH}	≤ ±20mV (at If=0A→If→0A)								
Insulation voltage	V _d	AC2500V for 1minute (sensing current 0.5mA), inside of through hole ⇔ terminal								
Insulation resistance	R _{IS}	≥ 500MΩ (at DC500V) , inside of through hole ⇔ terminal								
Ambient operation temperature	T _A	-10°C~+80°C								
Ambient storage temperature	T _S	-25°C~+85°C								

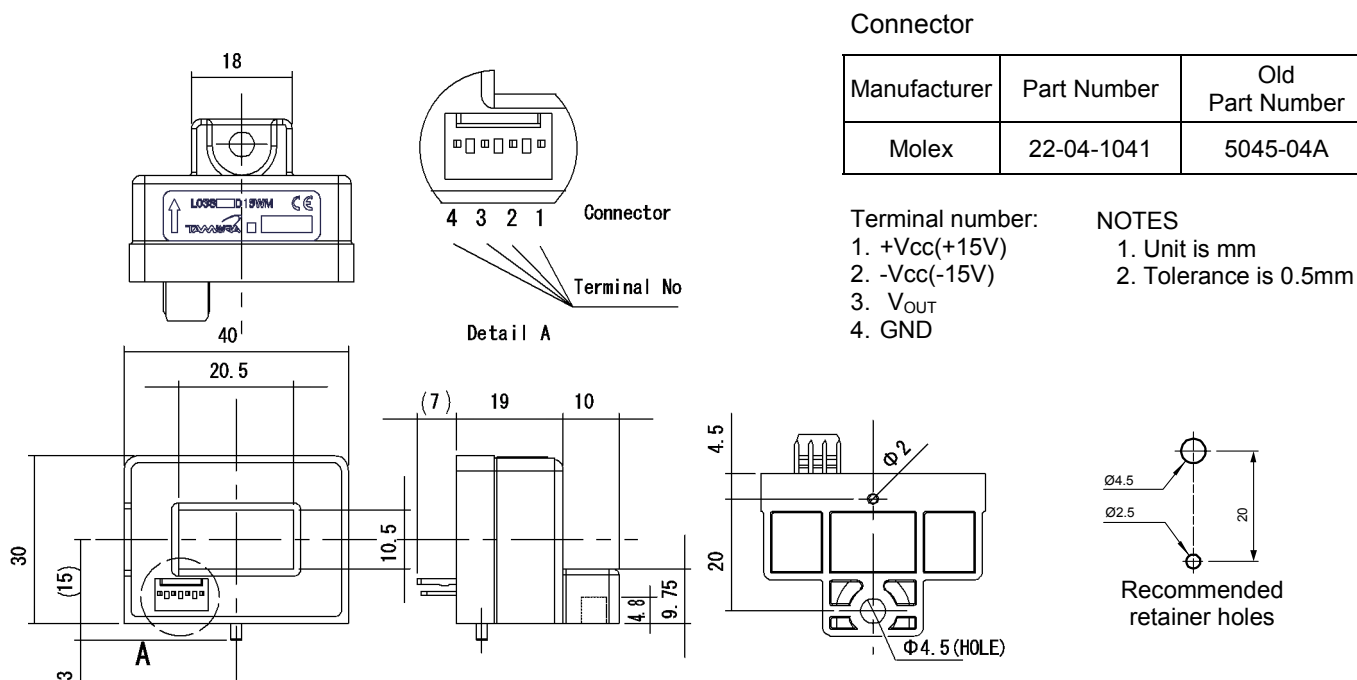
¹ After removal of core hysteresis — ² Without offset — ³ Time between 10% input current full scale and 90% of sensor output full scale — ⁴ Without Thermal drift of offset

Electrical Performances

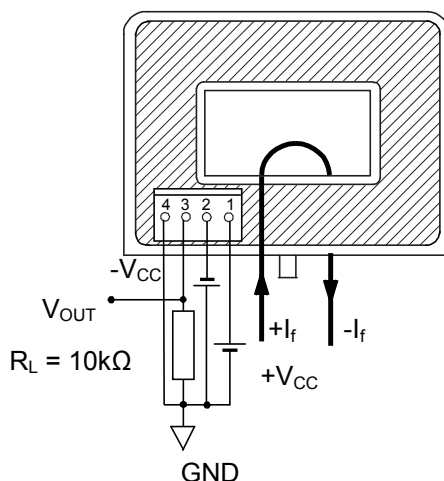


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Mechanical dimensions



Electrical connection diagram



Package & Weight Information

Weight	Pcs/box	Pcs/carton	Pcs/pallet
51g	20	200	3600

